

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	2693	((349/42) or (349/43)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:06
S2	0	("(sourceanddrain)near6buffer"). PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:06
S3	1456	(source and drain) near6 buffer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:07
S4	8	S1 and S3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:08
S5	997	buffer near6 (molybdenum or titanium or tantalum)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:27
S6	6	S1 and S5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:09
S7	9389	active near6 (molybdenum or titanium or tantalum)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:12
S8	0	active near6 (molybdenum or titanium or tantalum) near6 "contact resistance"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:12

S9	782	(molybdenum or titanium or tantalum) near6 "contact resistance"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:13
S10	11	S1 and S9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:17
S11	1410	(source and drain) near6 "contact resistance"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:18
S12	22	S1 and S11	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:24
S13	1	"10/028687"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:24
S14	132	(molybdenum or titanium or tantalum) near6 (cover\$3 or overlap\$3) near6 (source or drain)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:38
S15	24	349\$.ccls. and S14	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:35
S16	100	(buffer) near6 (cover\$3 or overlap\$3) near6 (source or drain)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:33

S17	6	349\$.ccls. and S16	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:38
S18	48	438\$.ccls. and S14	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:35
S19	26	(molybdenum or titanium or tantalum) near6 (cover\$3 or overlap\$3) near6 ("thin film transistor" TFT)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:42
S20	10	349\$.ccls. and S19	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:42
S21	7	438\$.ccls. and S19	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:41
S22	65	(molybdenum or titanium or tantalum) near16 (cover\$3 or overlap\$3) near16 ("thin film transistor" TFT)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:58
S23	15	349\$.ccls. and S22	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:43
S24	41	S22 not @ad>"20010605"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:49

S25	12231	(molybdenum or titanium or tantalum) same (("thin film transistor" TFT) or (source and drain))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:59
S26	456	S1 and S25	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 10:59
S27	2423	((molybdenum or titanium or tantalum) same (("thin film transistor" TFT) or (source and drain))) same resistance	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 11:22
S28	67	S1 and S27	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 11:00
S29	29	S28 not @ad>"20010605"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 11:26
S30	1357	((molybdenum or titanium or tantalum) same (over or above) near6 (("thin film transistor" TFT) or (source and drain)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 11:23
S31	337	((molybdenum or titanium or tantalum) near6 (over or above) near6 (("thin film transistor" TFT) or (source and drain)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 11:23
S32	3	S1 and S31	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 11:26

S33	50	S1 and S30	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 11:26
S34	26	S33 not @ad>"20010605"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 11:40
S35	109	(passivation or protective) near6 (cover\$3 or overlap\$3) near6 (source and drain and pixel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 11:42
S36	49	S1 and S35	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 11:40
S37	17	S36 not @ad>"20010605"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 11:42
S38	73	(passivation or protective) near6 (above or over) near6 (source and drain and pixel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 11:42
S39	24	S1 and S38	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 11:42
S40	13	S39 not @ad>"20010605"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 12:14

S41	37	buffer near6 (cover\$3 or overlap\$3) near6 (source and drain)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 12:15
S42	18	S41 not @ad>"20010605"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 12:29
S43	129	(passivat\$4 or protect\$3) near6 (cover\$3 or overlap\$4) near6 (source and drain and pixel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 12:28
S44	86	349\$.ccls. and S43	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 12:28
S45	28	S44 not @ad>"20010605"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/28 12:29